

Spring 2002



EEE598D: Analog Filters & Signal Processing Circuits

Instructor:

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Today: Active RC and MOS-C Filter Design

Basic Filter Structures

First-Order Filters

Second-Order Filters

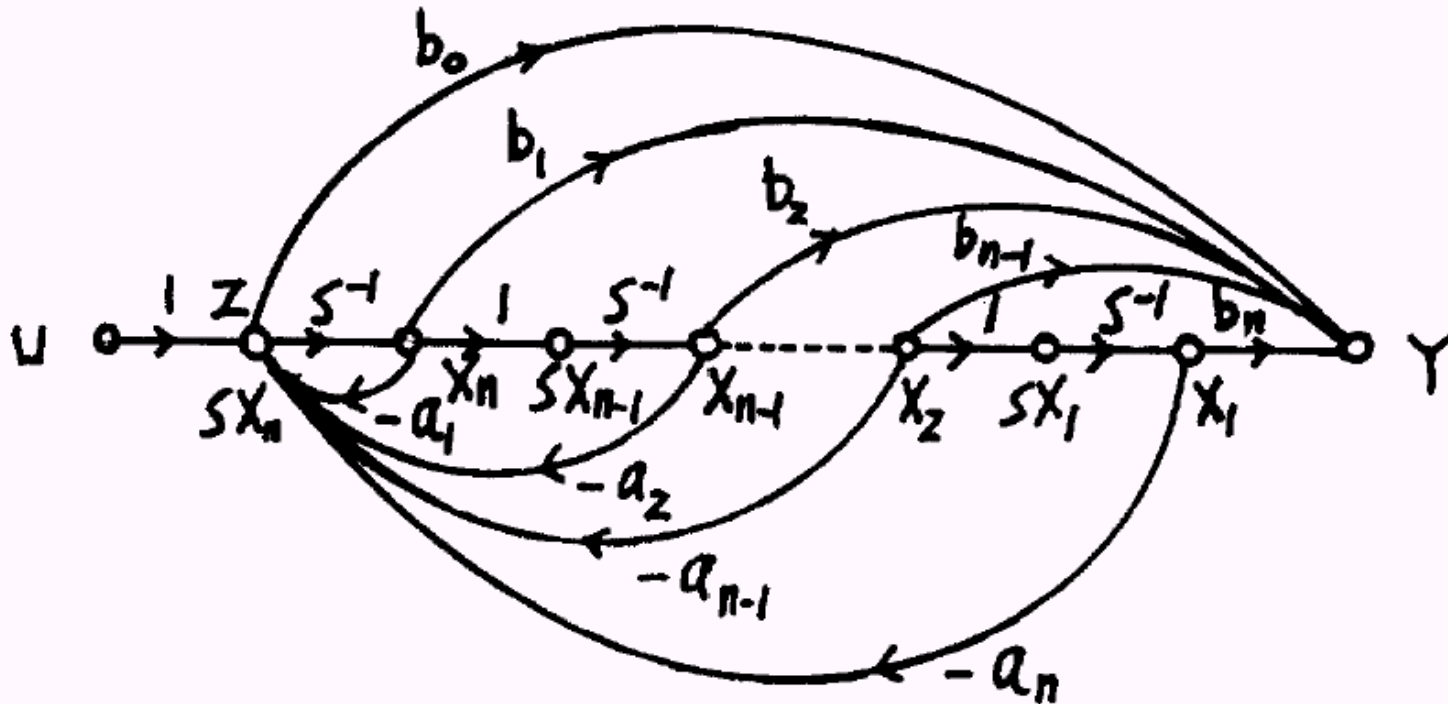
Cascaded Design of High-Order Filters

Basic Circuit Elements



- Opamps
 - Isolation/Decoupling between stages
 - Gain
 - Inversion
- Capacitor
 - Integration
- Resistor/MOS-VCR
 - Linear conversion
 - Tuning

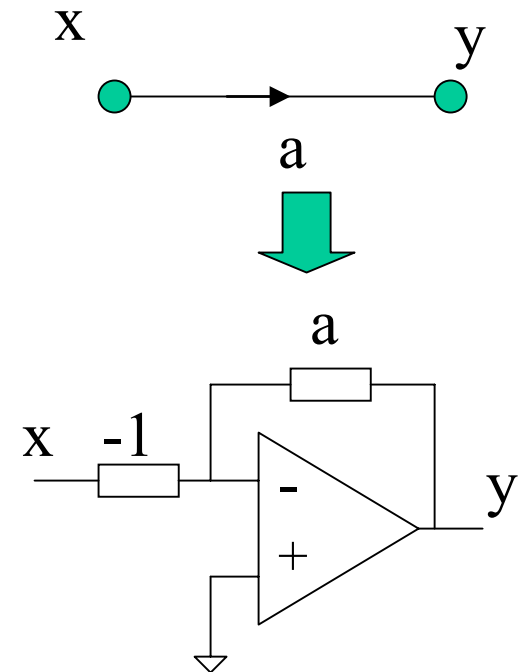
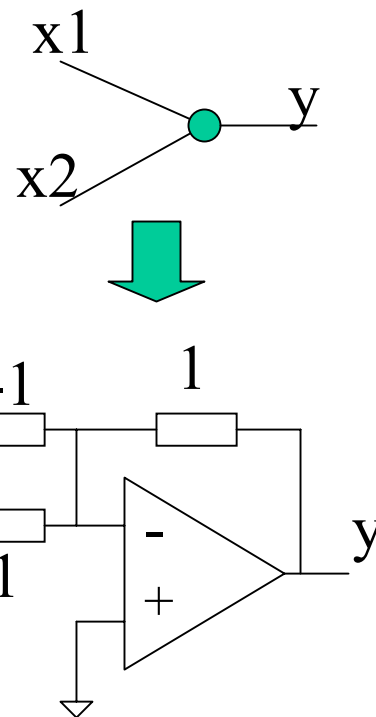
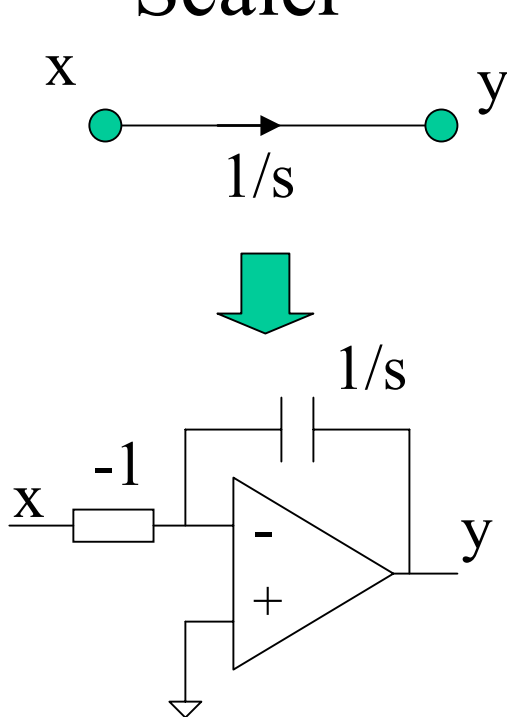
General CT Filter Structure



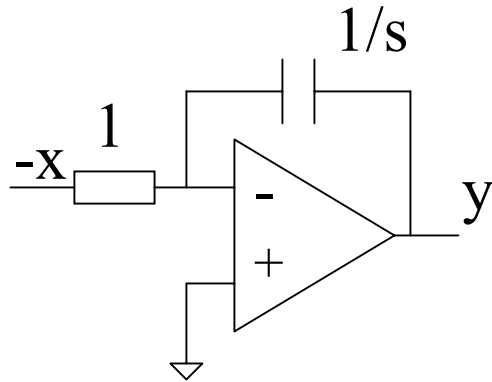
$$H(S) = \frac{Y(s)}{U(s)} = \frac{b_0 S^n + b_1 S^{n-1} + \dots + b_n}{S^n + a_1 S^{n-1} + \dots + a_n}$$

Basic Filter Elements

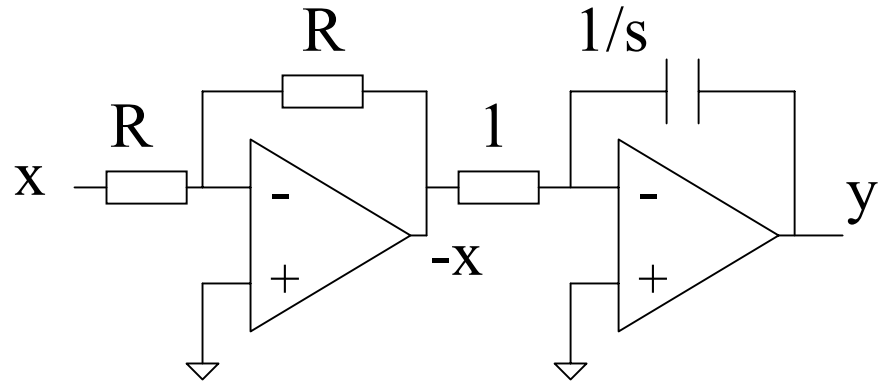
- Integrator
- Adder
- Scaler



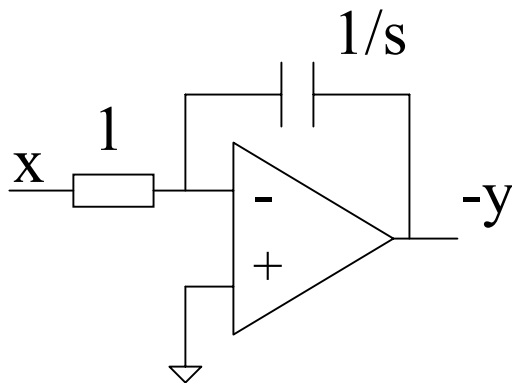
Active RC Integrator Structures



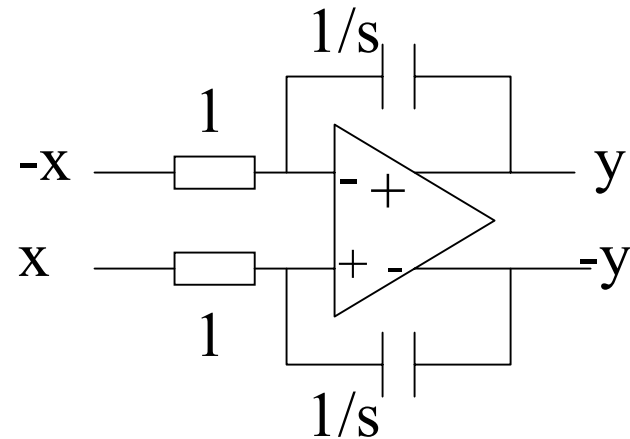
A) Inverted input



C) Internal inversion

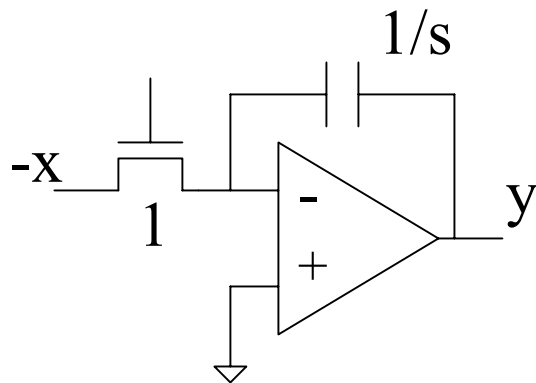


B) Inverted output

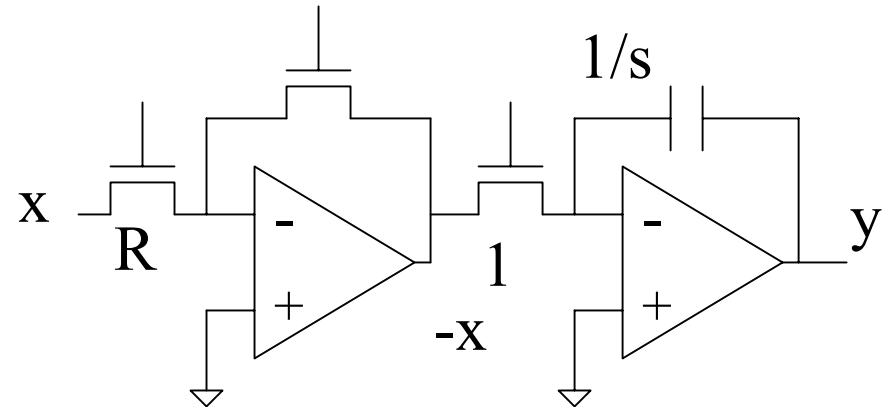


D) Fully differential

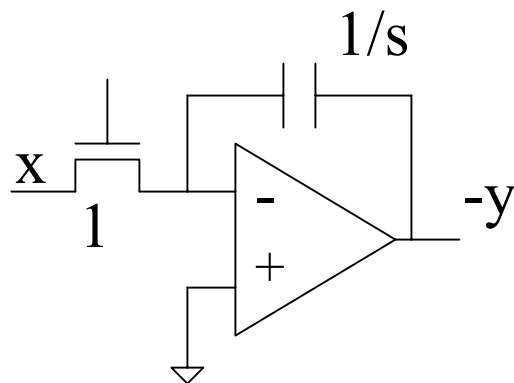
MOS-C Integrator Structures (I)



A) Inverted input



C) Internal inversion



B) Inverted output

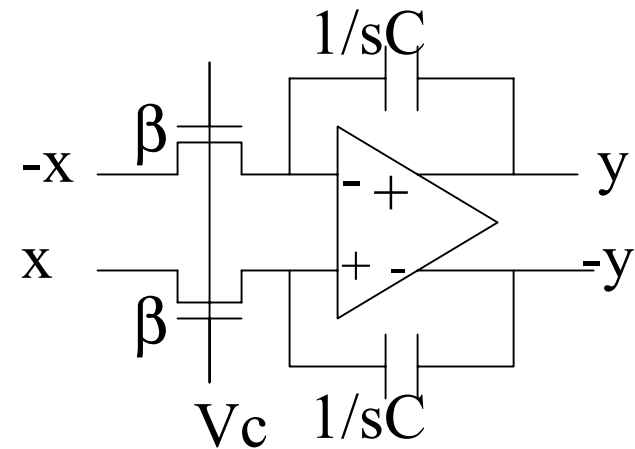
Single-end & Single Transistor

- Simple
- Small
- Tunable
- Poor Linearity
- Poor PSRR

MOS-C Integrator Structures (II)



- Fully Differential 2-Transistor
 - Improved Linearity
 - Improved PSRR
 - Tunable

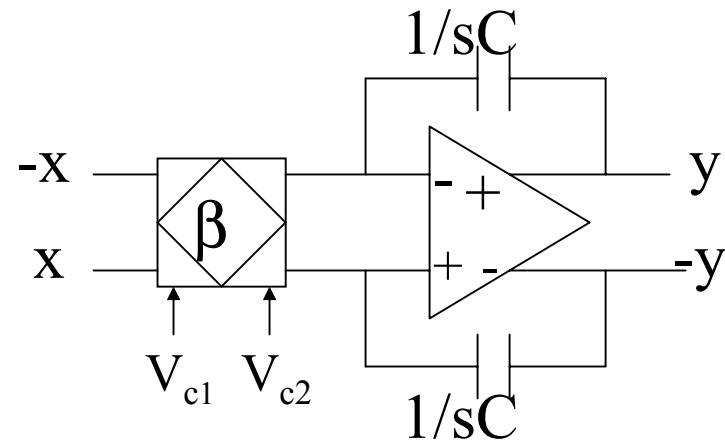


$$H(s) = \frac{1}{s \frac{C}{\beta (V_C - V_T)}}$$

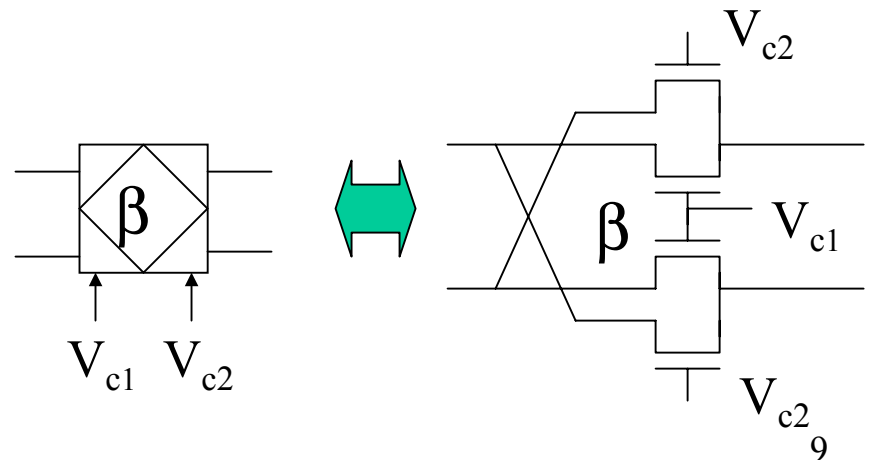
MOS-C Integrator Structures (III)

- Fully Differential 4-Transistor

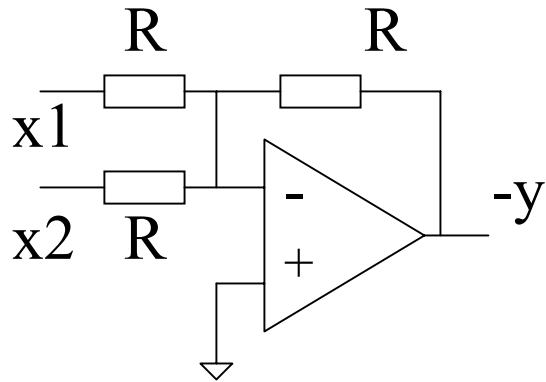
- Better Linearity
- Better PSRR
- Tunable
- Large Area



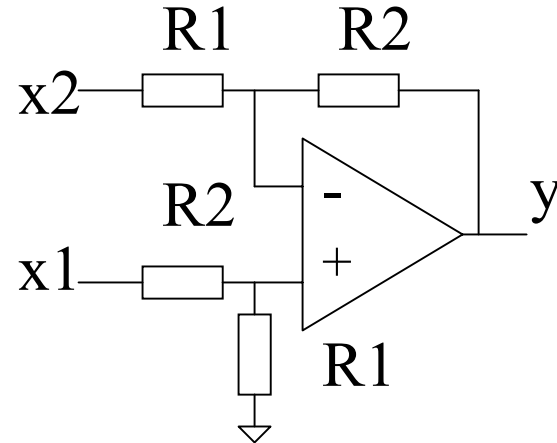
$$H(s) = \frac{1}{s \frac{C}{\beta (V_{c1} - V_{c2})}}$$



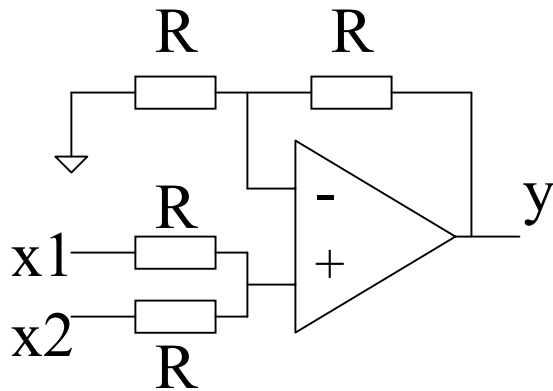
Active RC Adder/Subtractor Structures



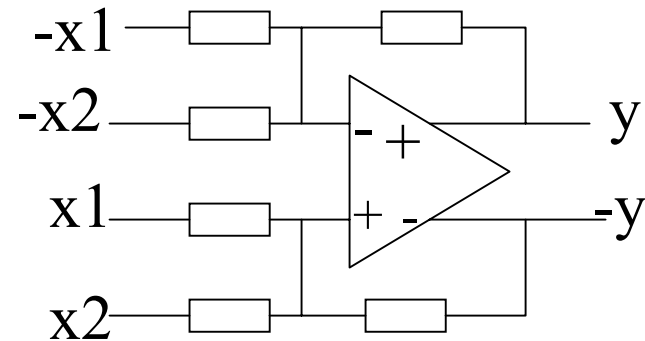
A) Inverted Addition



C) Subtraction

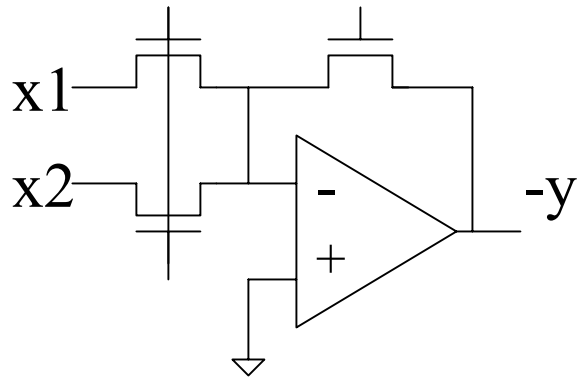


B) Addition

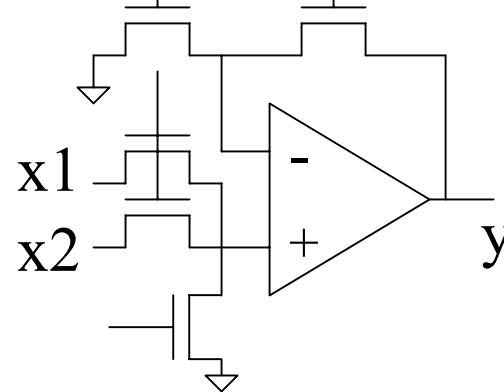


D) Differential addition/subtraction

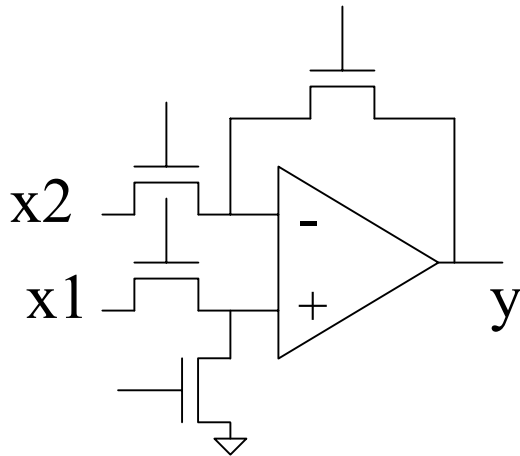
MOS-C Adder/Subtractor Structures (I)



A) Inverted addition



C) Non-inverted addition



B) Subtraction

Single-end & Single Transistor

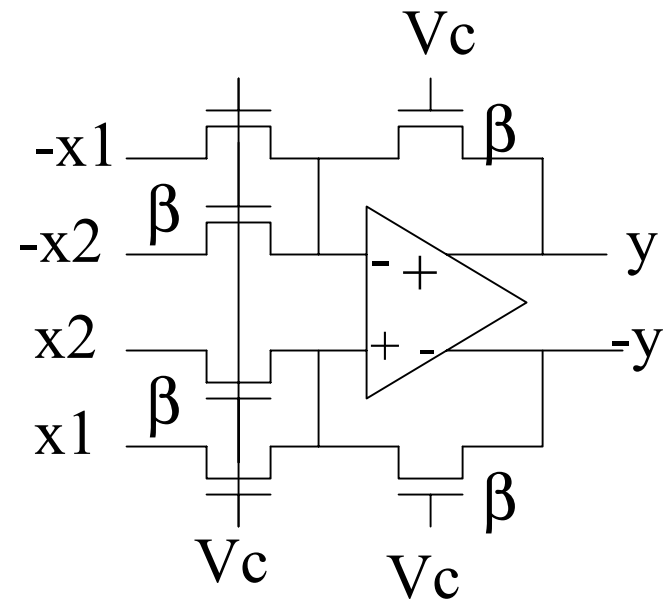
- Simple
- Small
- Tunable
- Poor Accuracy
- Poor PSRR

MOS-C Adder/Subtractor Structures (II)

- Fully Differential 2-Transistor

- Improved Linearity
- Improved PSRR
- Tunable

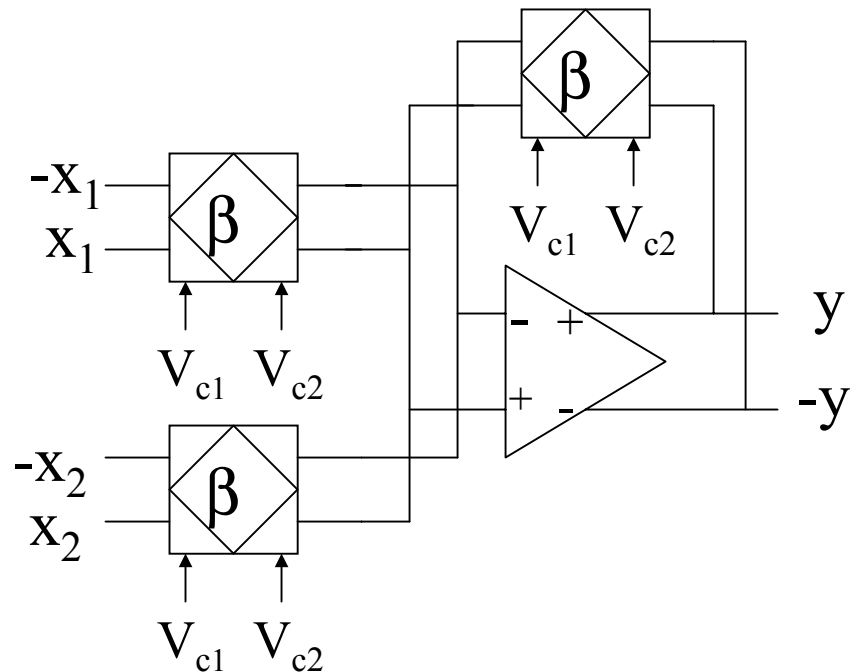
$$y = x_1 + x_2$$



MOS-C Adder/Subtractor Structures (III)



- Fully Differential 4-Transistor
 - Better Linearity
 - Better PSRR
 - Tunable
 - Large Area



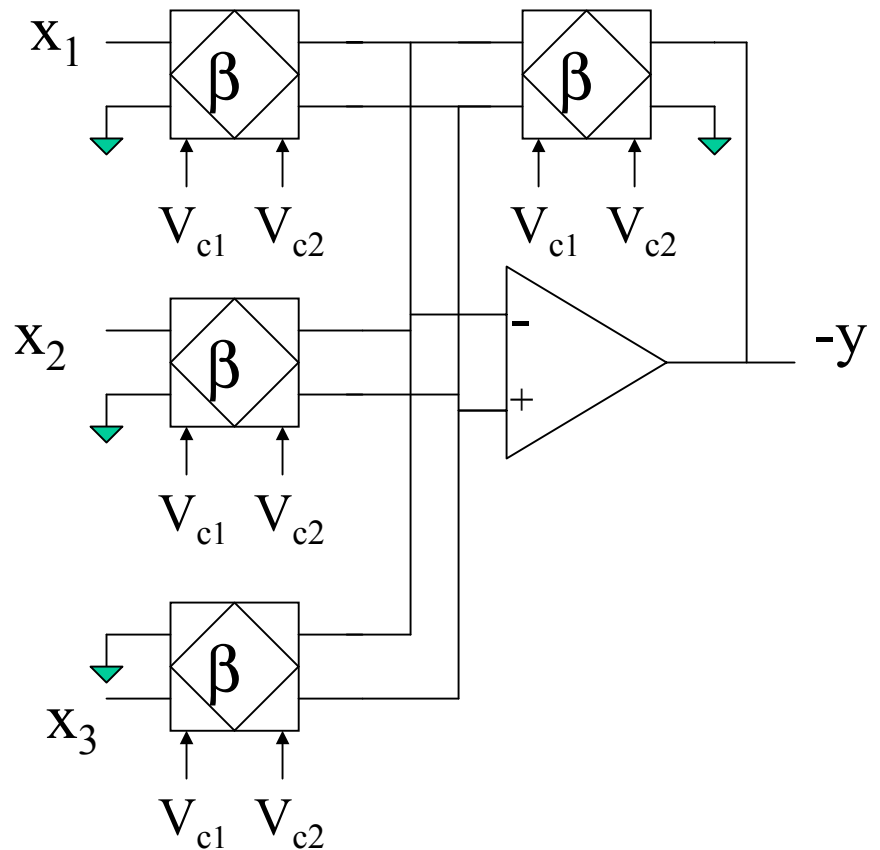
$$y = x_1 + x_2$$

MOS-C Adder/Subtractor Structures (IV)

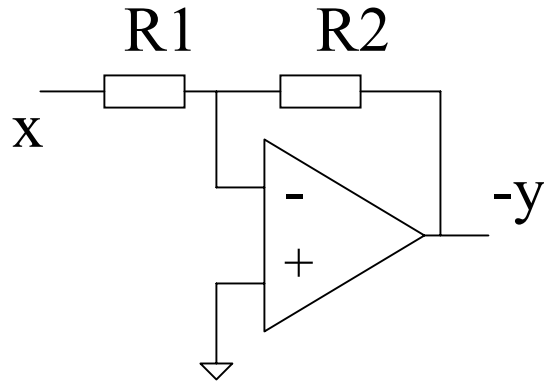


- Single-ended 4-Transistor
 - Good Linearity
 - Tunable
 - Smaller area

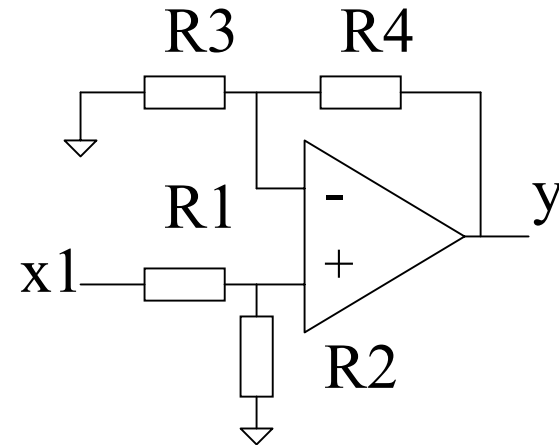
$$y = x_1 + x_2 - x_3$$



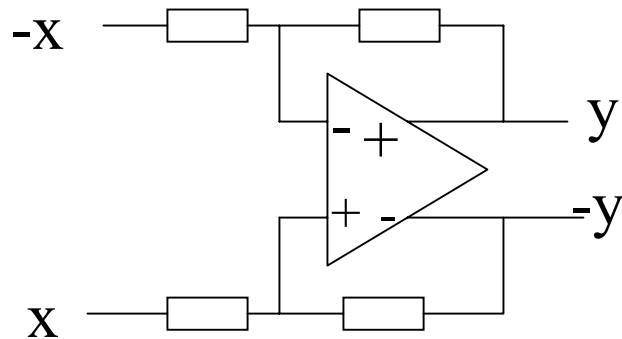
Active RC Scaler Structures



A) Inverted



B) non-inverted



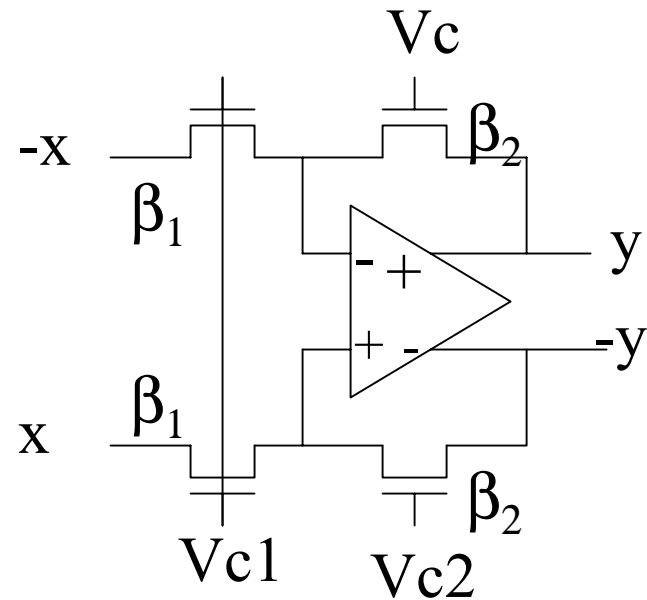
C) Fully Differential

MOS-C Scaler Structures (I)



- Fully Differential 2-Transistor

$$\frac{y}{X} = \frac{\beta_1 (V_{c1} - V_T)}{\beta_2 (V_{c2} - V_T)}$$

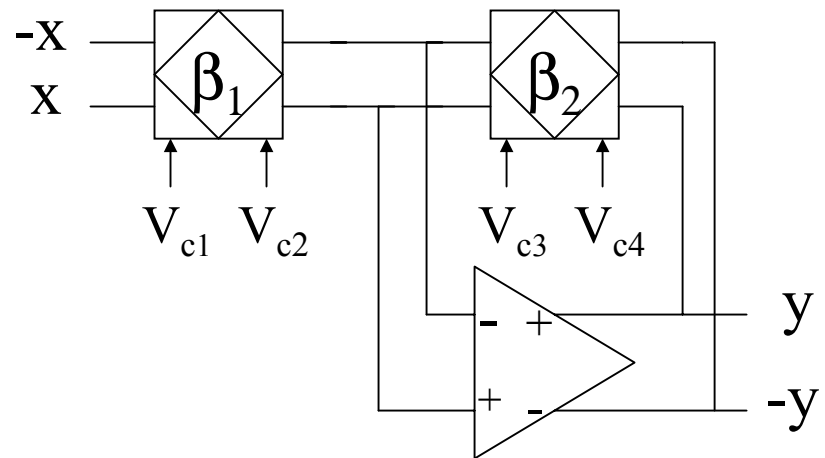


MOS-C Scaler Structures (II)



- Fully Differential 4-Transistor VCR

$$\frac{y}{X} = \frac{\beta_1 (V_{c1} - V_{c2})}{\beta_2 (V_{c3} - V_{c4})}$$

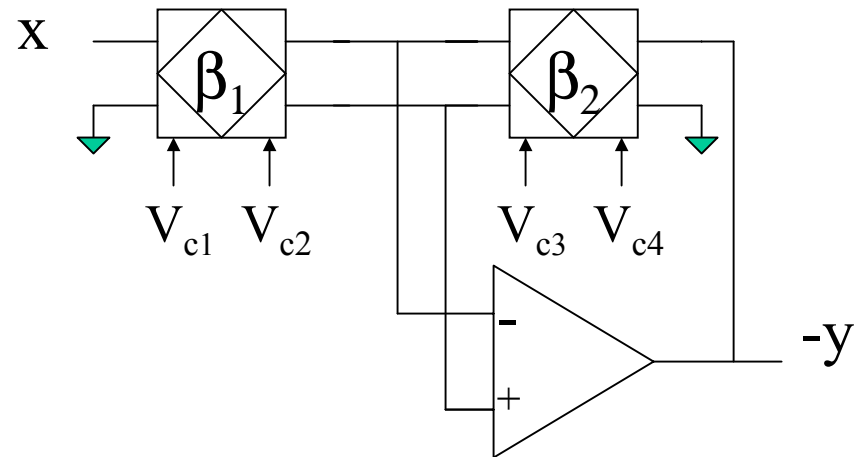


MOS-C Scaler Structures (III)



- Single-ended 4-Transistor VCR

$$\frac{y}{X} = \frac{\beta_1 (V_{c1} - V_{c2})}{\beta_2 (V_{c3} - V_{c4})}$$



First-Order Filters

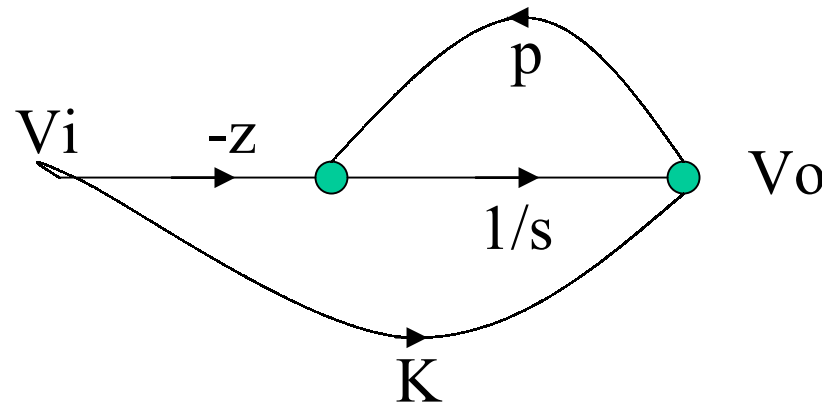


- TF and SFG

$$H(s) = K \frac{s - z}{s - p}$$

pole : $s = p < 0$

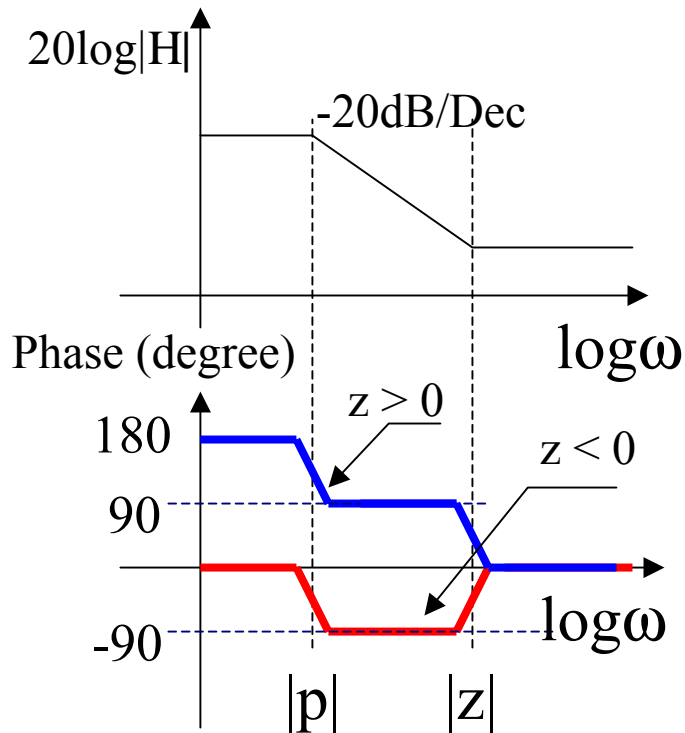
zero: $s = z$



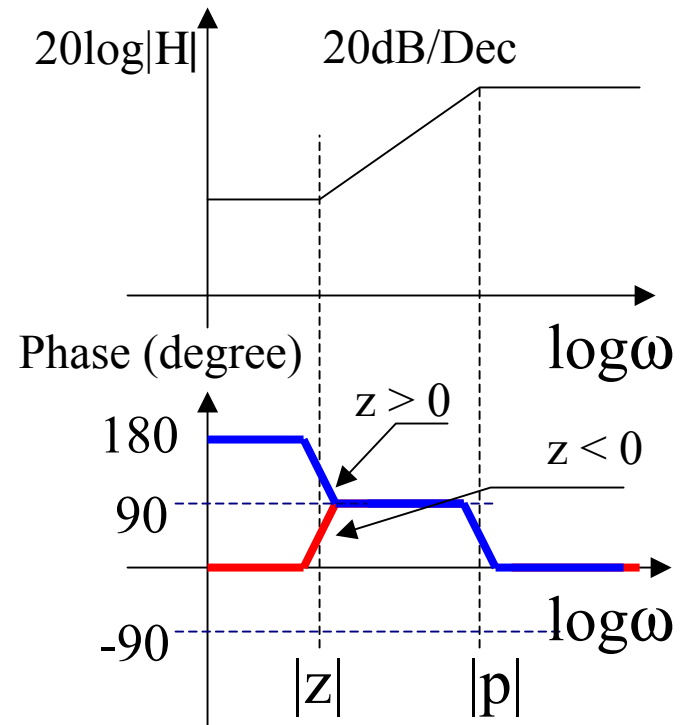
First-Order Filters



- Bode Plots



A) $|p| < |z|, K > 0$

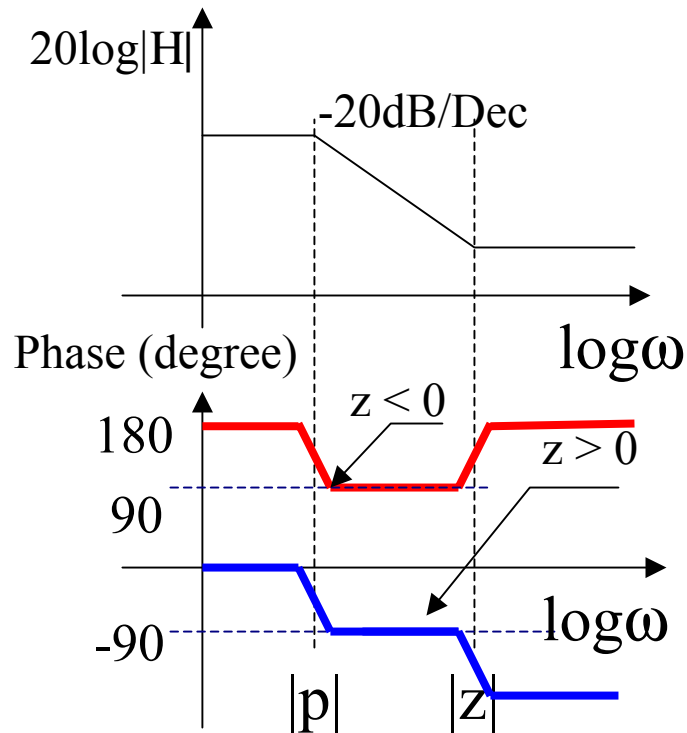


B) $|p| > |z|, K > 0$

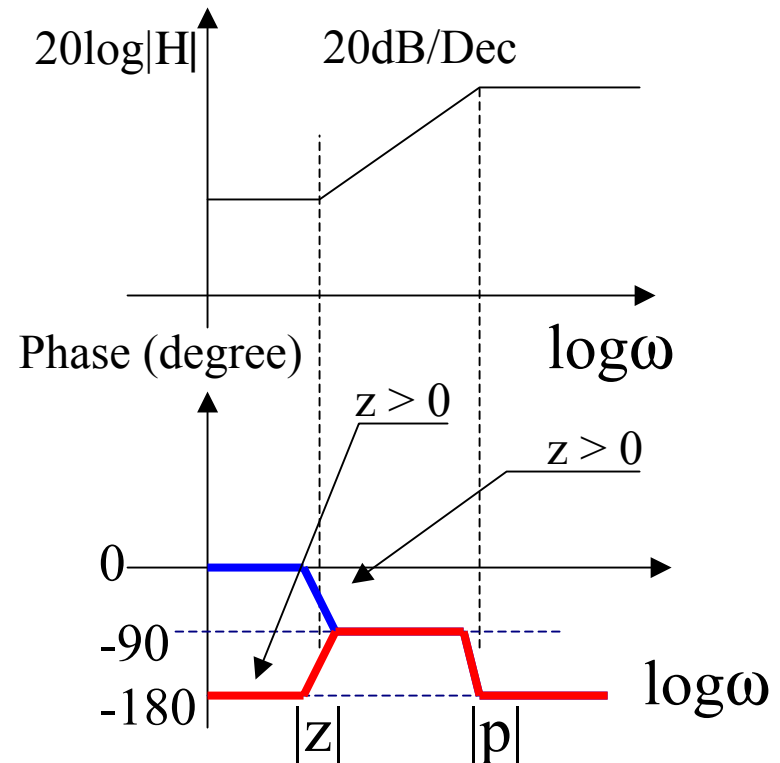
First-Order Filters



- Bode Plots



A) $|p| < |z|$, $K < 0$



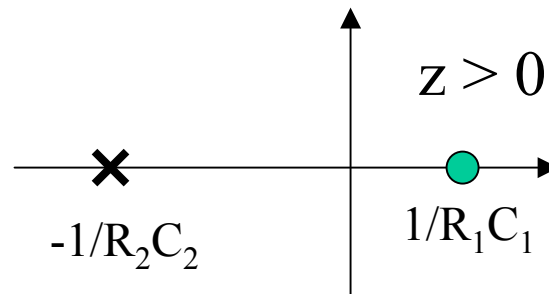
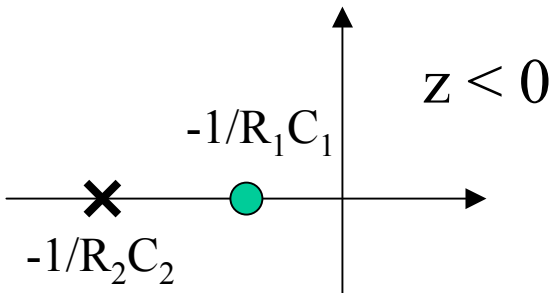
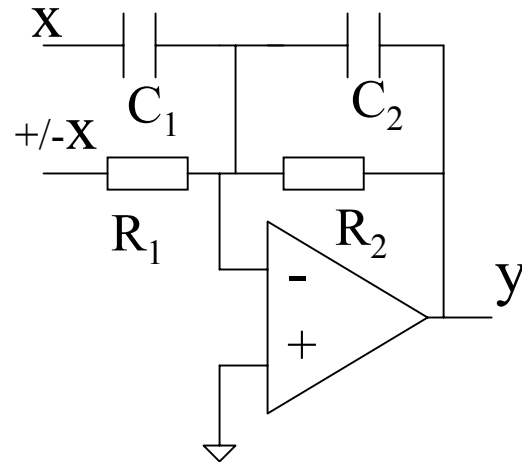
B) $|p| > |z|$, $K < 0$

First-Order Active RC Filters



- Single-ended

$$H(s) = -\frac{C_1}{C_2} \frac{s \pm \frac{1}{R_1 C_1}}{s + \frac{1}{R_2 C_2}}$$

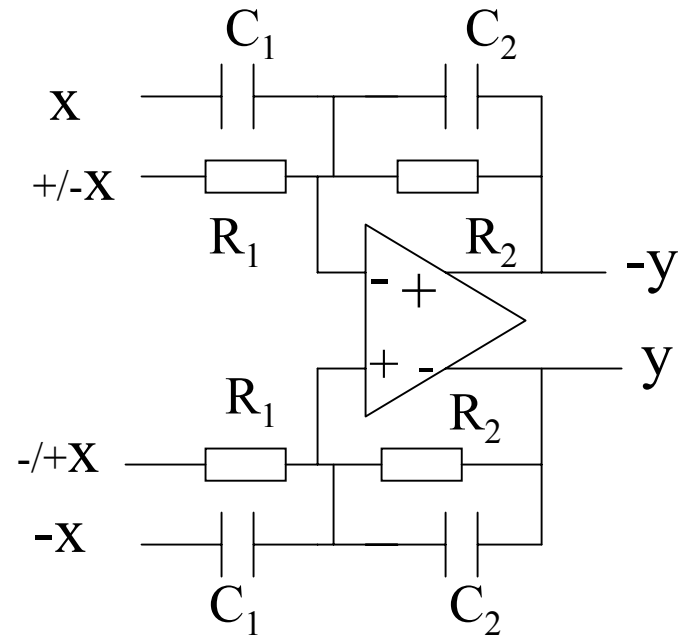


First-Order Active RC Filters



- Fully differential

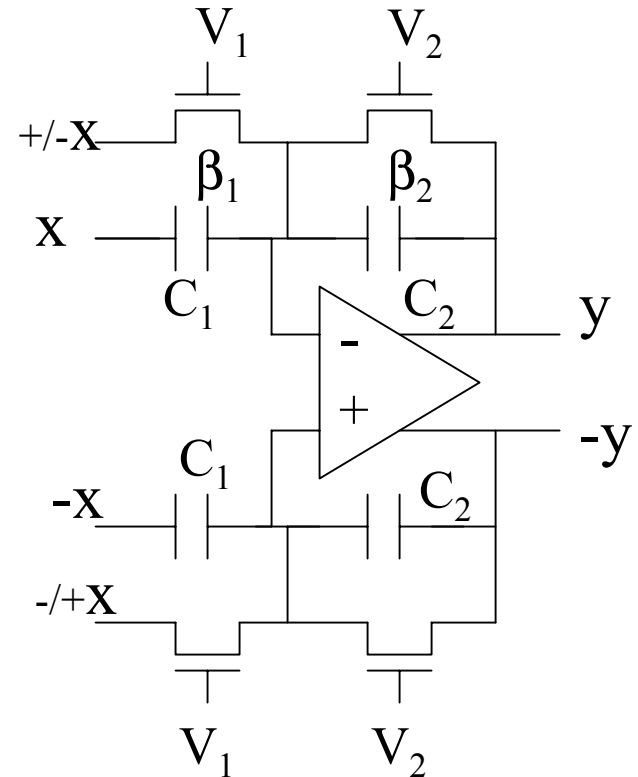
$$H(s) = \frac{C_1}{C_2} \frac{s \pm \frac{1}{R_1 C_1}}{s + \frac{1}{R_2 C_2}}$$



First-Order MOS-C Filters

- Fully differential 2-transistor VCR

$$H(s) = \frac{C_1}{C_2} \frac{s \pm \frac{\beta_1(V_1 - V_T)}{C_1}}{s + \frac{\beta_2(V_2 - V_T)}{C_2}}$$

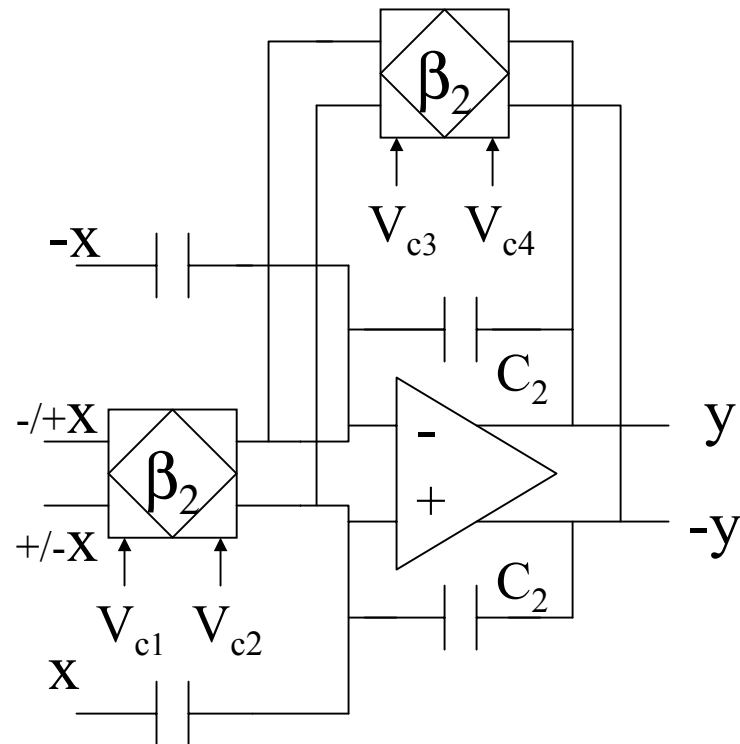


First-Order MOS-C Filters



- Fully differential 4-transistor VCR

$$H(s) = \frac{C_1}{C_2} \frac{s \pm \frac{\beta_1(V_{c1} - V_{c2})}{C_1}}{s + \frac{\beta_2(V_{c3} - V_{c4})}{C_2}}$$



Second-Order Filters

- LP prototype

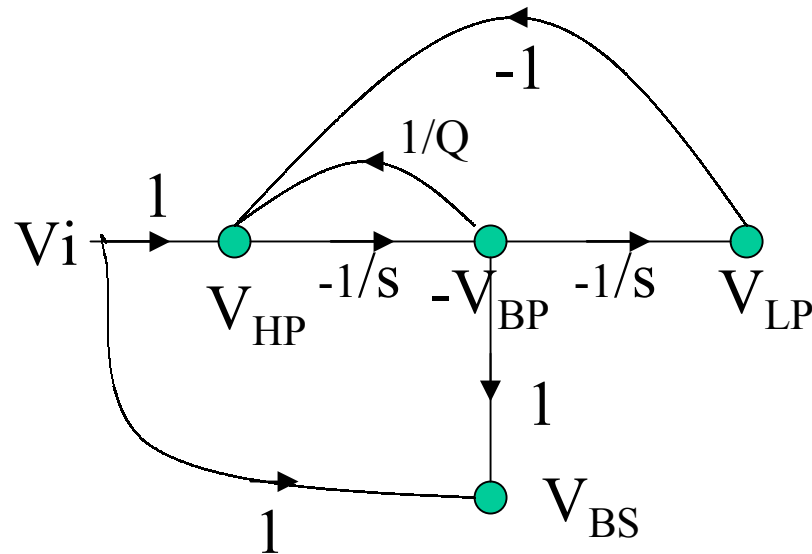
$$H_{LP}(s) = \frac{1}{s^2 + \frac{1}{Q}s + 1}$$

- HP

$$H_{HP}(s) = \frac{s^2}{s^2 + \frac{1}{Q}s + 1}$$

- BP

$$H_{BP}(s) = \frac{s}{s^2 + \frac{1}{Q}s + 1}$$



Second-Order Filters



- BS

$$H_{BS}(s) = \frac{s^2 + 1}{s^2 + \frac{1}{Q}s + 1}$$

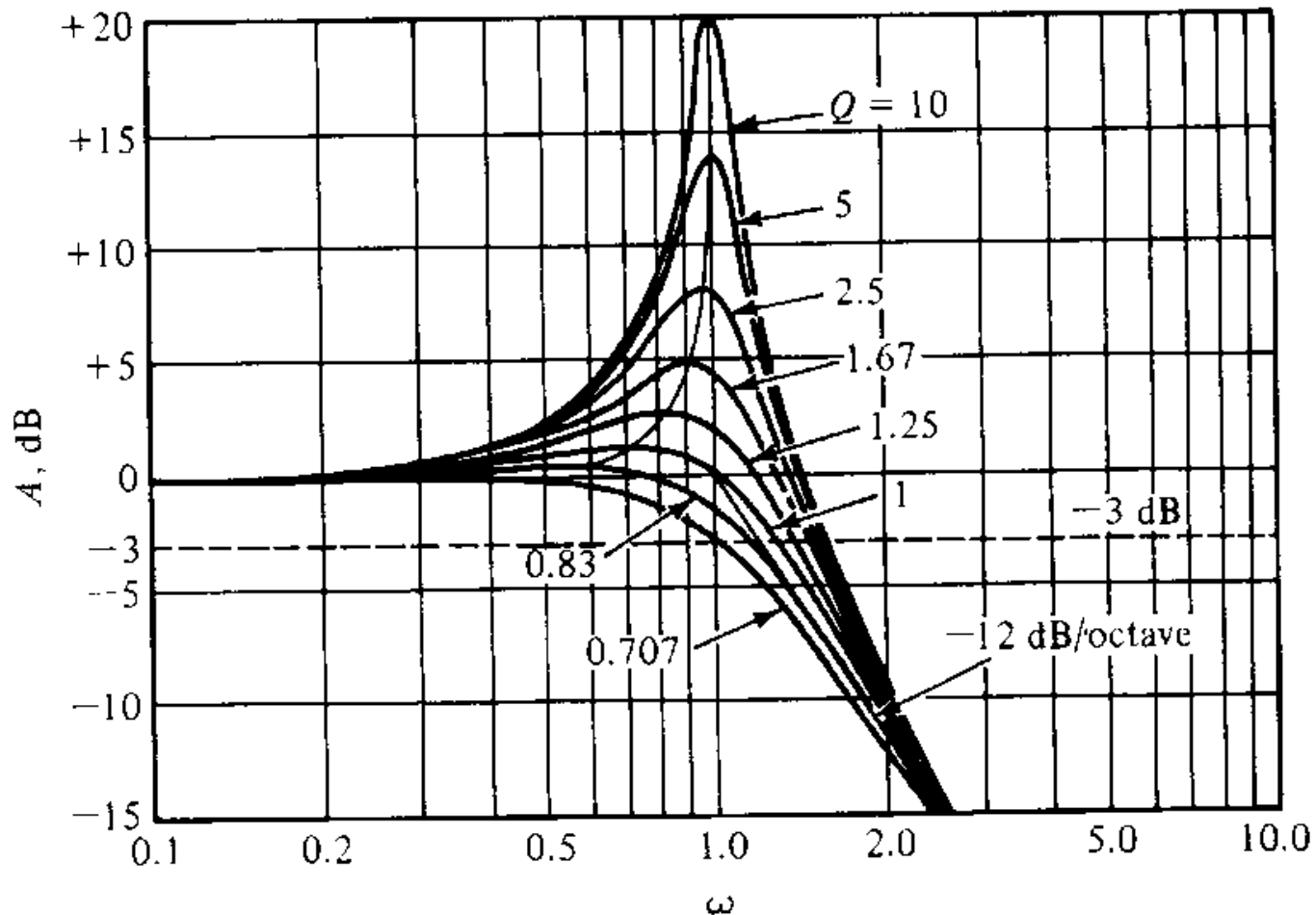
- AP

$$H_{HP}(s) = \frac{s^2 - \frac{1}{Q}s + 1}{s^2 + \frac{1}{Q}s + 1}$$

Second-Order Filters



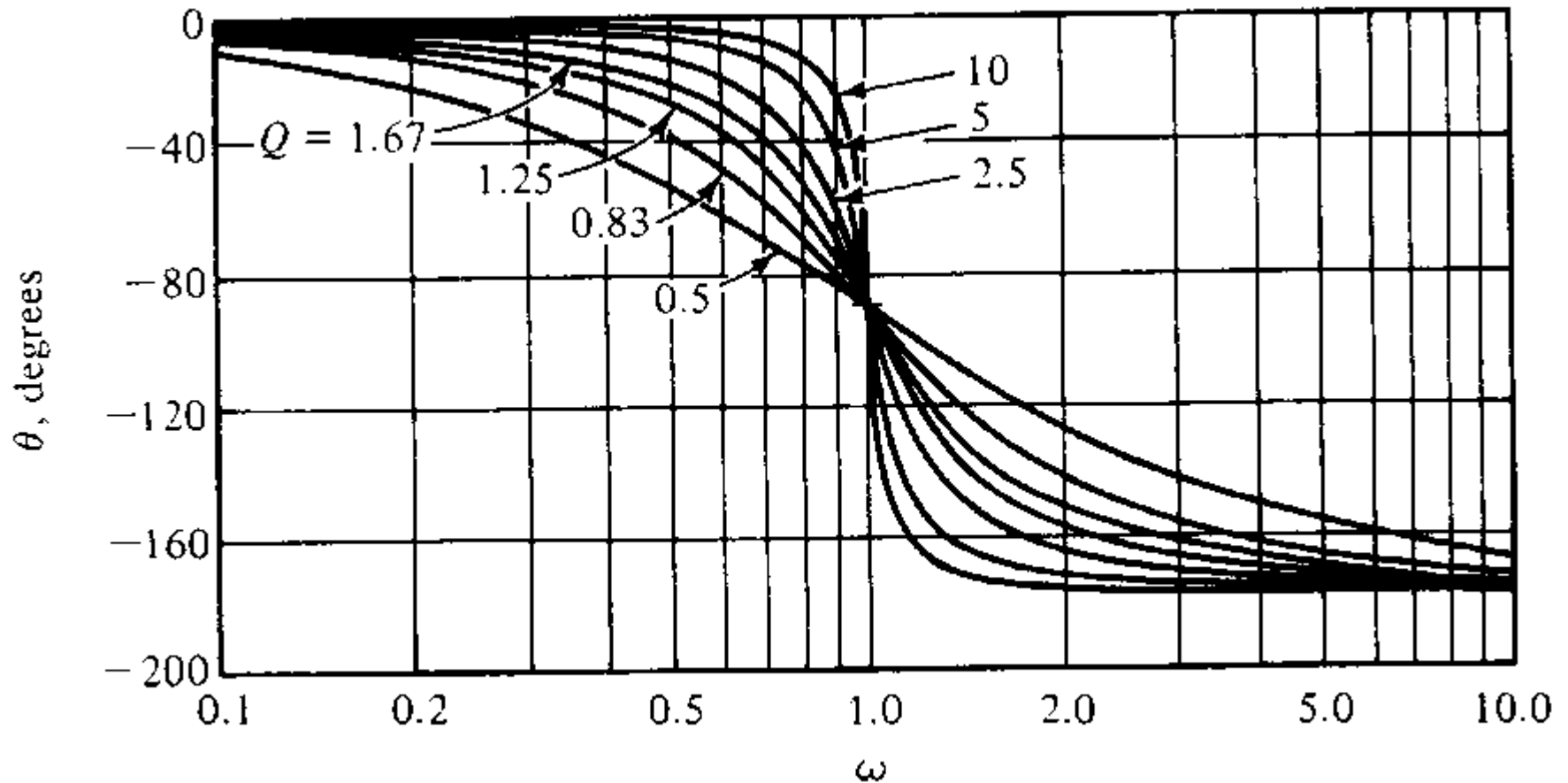
- Bode Plots (LP)



Second-Order Filters



- Bode Plots (LP)

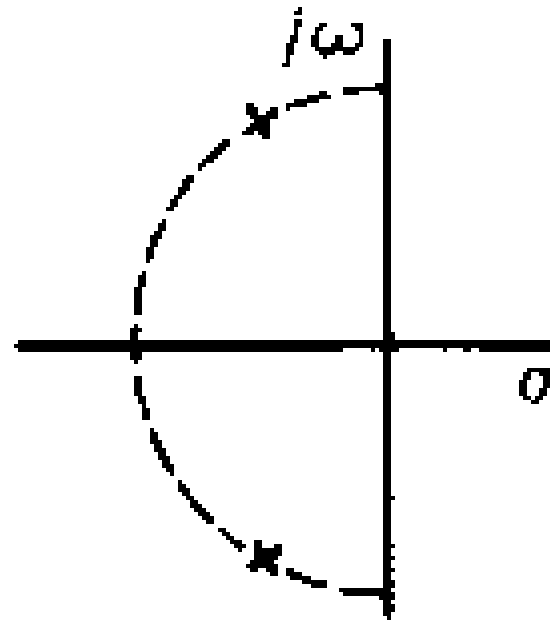
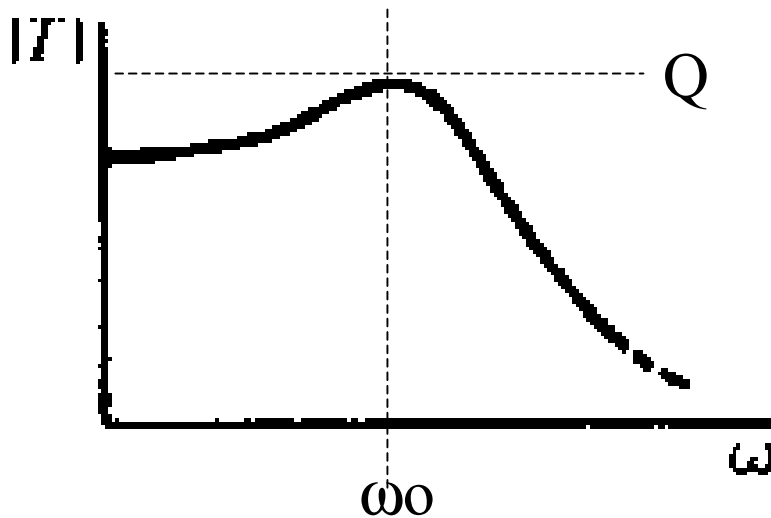


Second-Order Filters



- Bode Plots (LP)

$$T_{LP} = \frac{\omega_0^2}{s^2 + \frac{\omega_0}{Q}s + \omega_0^2}$$

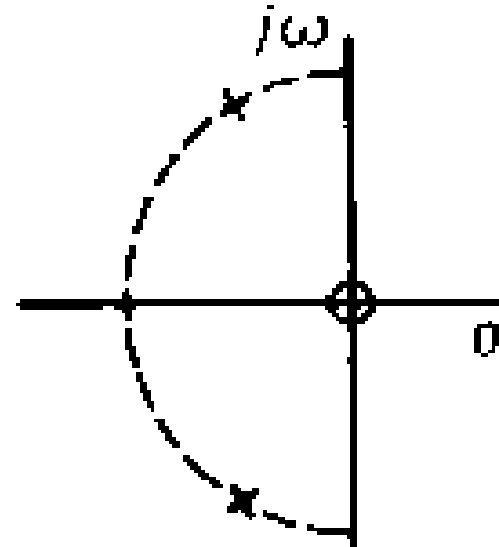
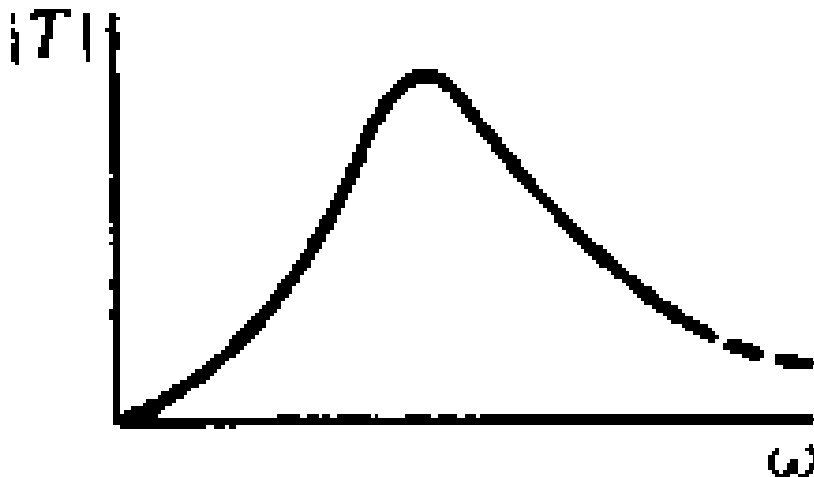


Second-Order Filters



- Bode Plots (BP)

$$T_{BP} = \frac{\frac{\omega_0}{Q} s}{s^2 + \frac{\omega_0}{Q} s + \omega_0^2}$$

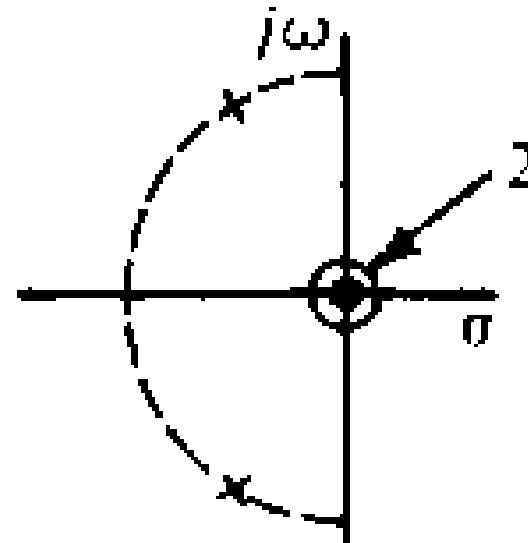
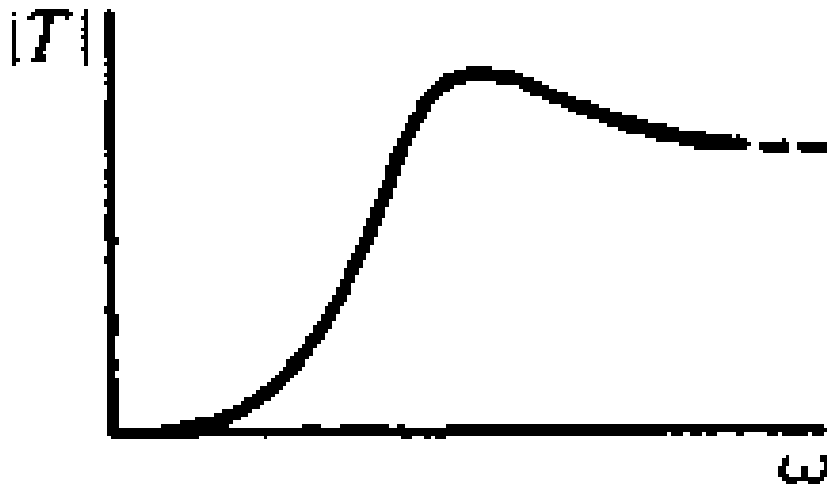


Second-Order Filters



- Bode Plots (HP)

$$T_{HP} = \frac{s^2}{s^2 + \frac{\omega_0}{Q}s + \omega_0^2}$$

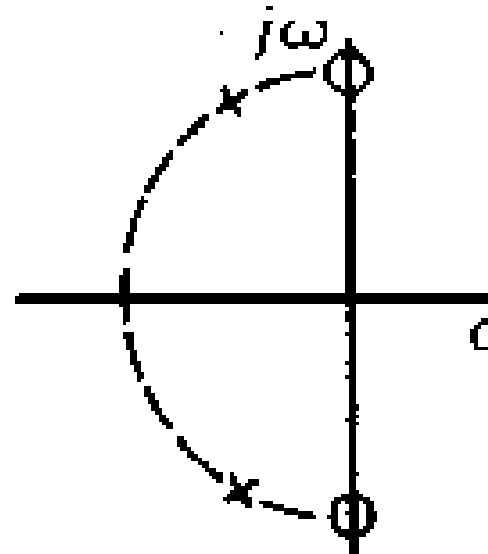
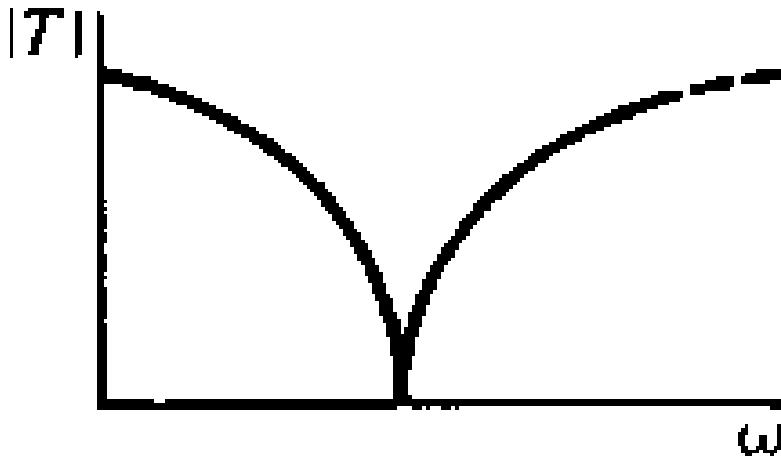


Second-Order Filters



- Bode Plots (BS)

$$T_{BE} = \frac{s^2 + \omega_0^2}{s^2 + \frac{\omega_0}{Q}s + \omega_0^2}$$

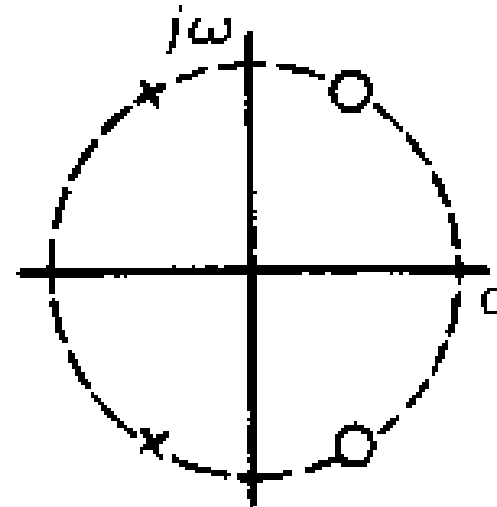
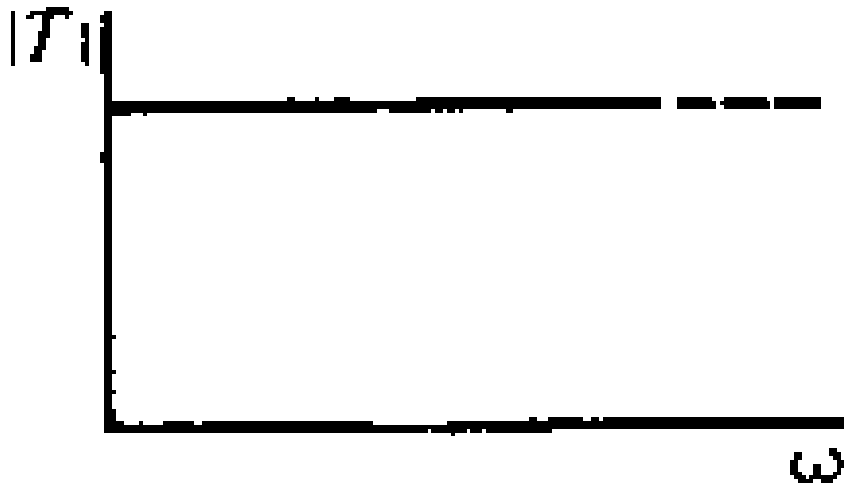


Second-Order Filters



- Bode Plots (AP)

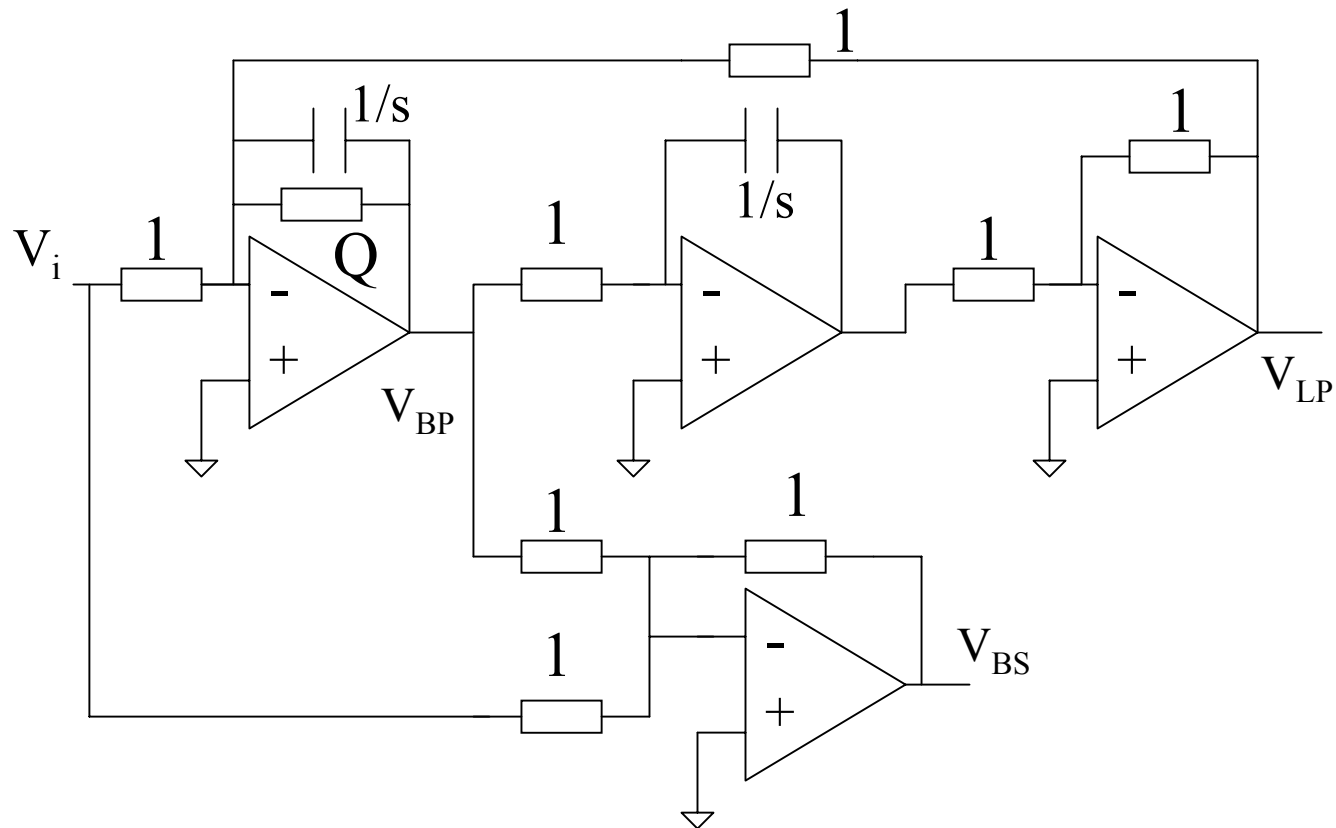
$$T_{AP} = \frac{s^2 - \frac{\omega_0}{Q}s + \omega_0^2}{s^2 + \frac{\omega_0}{Q}s + \omega_0^2}$$



Second-Order Active RC Filters



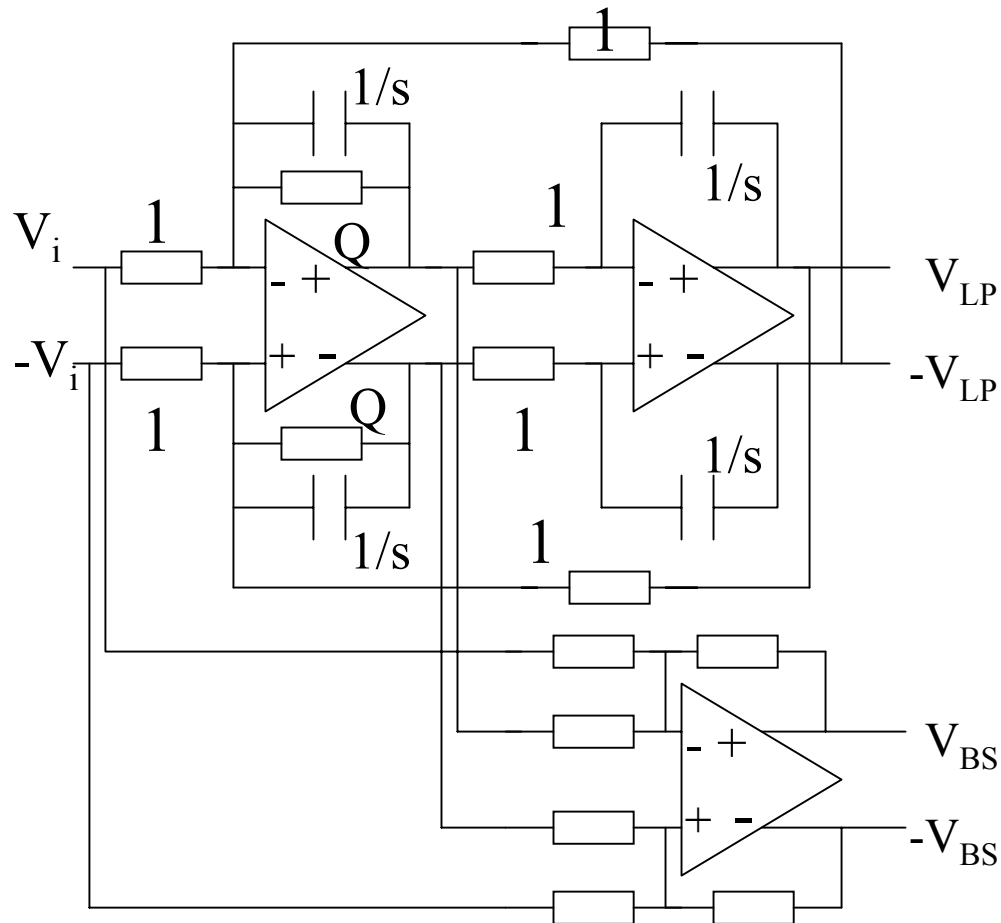
- Single-ended



Second-Order Active RC Filters



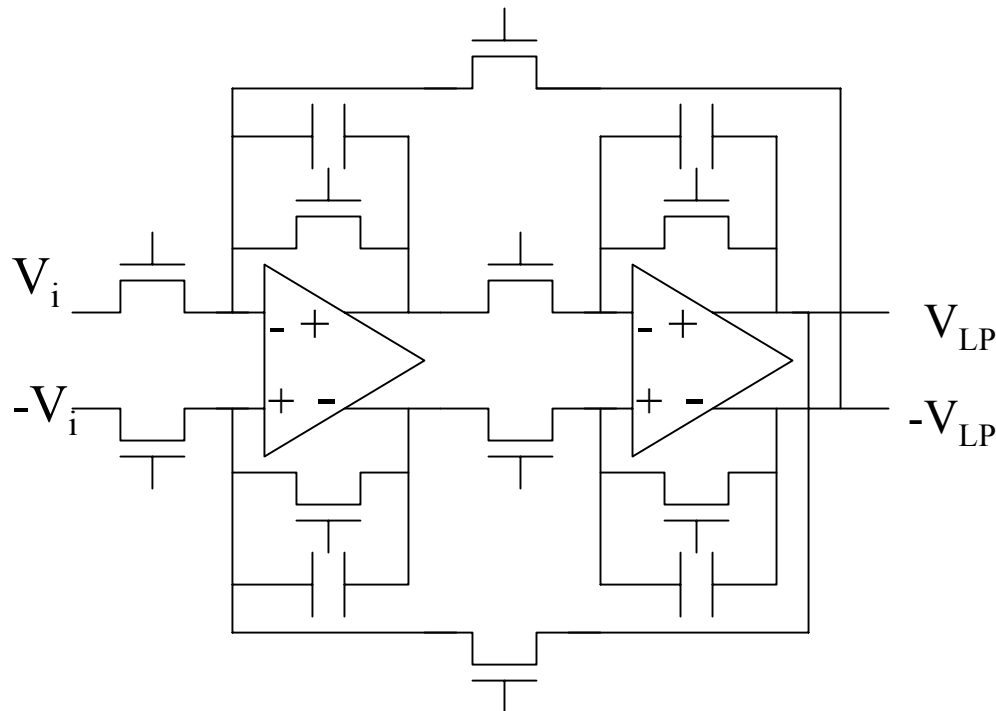
- Fully differential



Second-Order MOS-C Filters



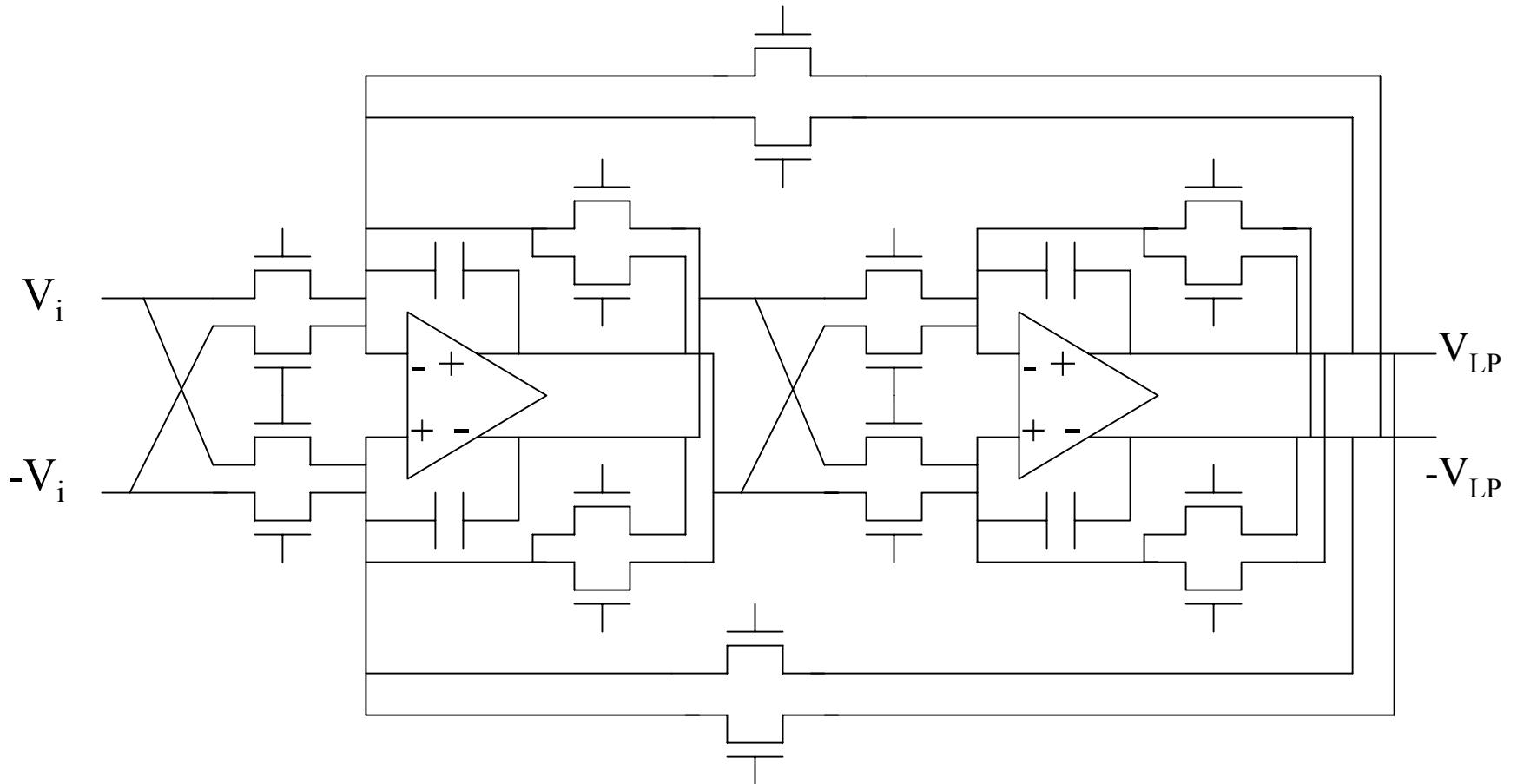
- Fully differential 2-transistor



Second-Order MOS-C Filters



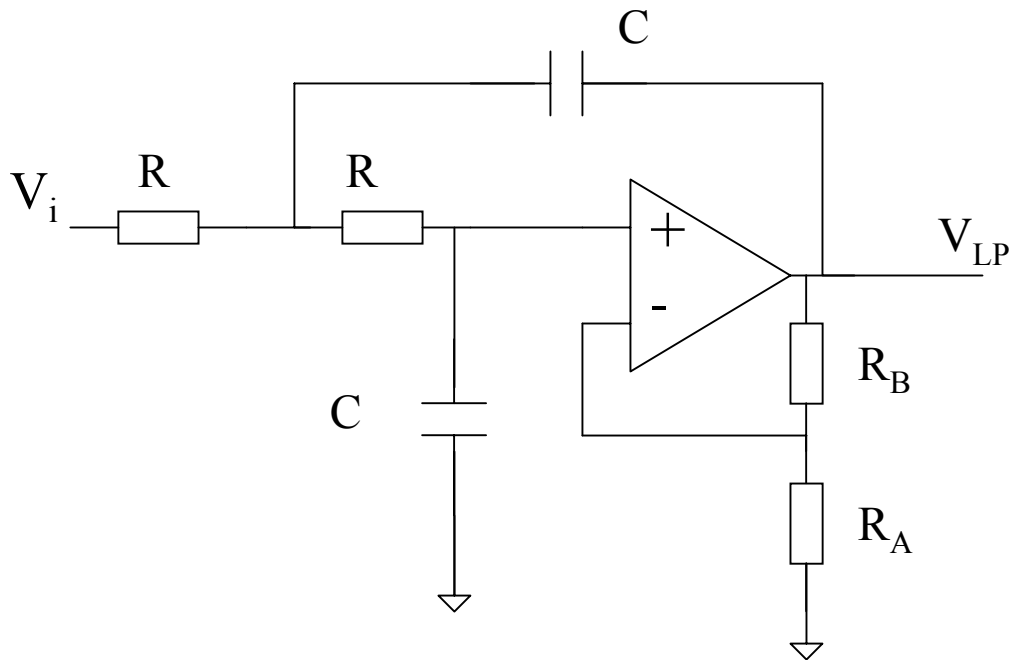
- Fully differential 4-transistor



Second-Order Active RC Filters



- Sallen-Key Circuits(I)



$$H_{LP}(s) = \frac{K}{\left(\frac{s}{\omega_o}\right)^2 + \frac{1}{Q}\left(\frac{s}{\omega_o}\right) + 1}$$

$$\omega_o = 1/RC$$
$$K = 1 + R_B / R_A$$
$$Q = 1/(3 - K)$$

Second-Order Active RC Filters

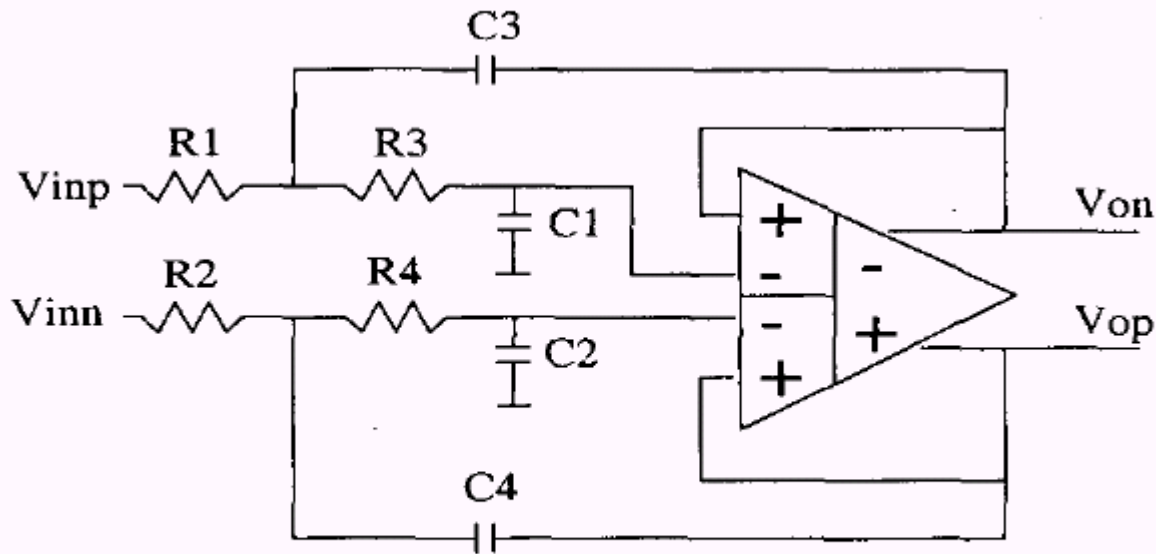
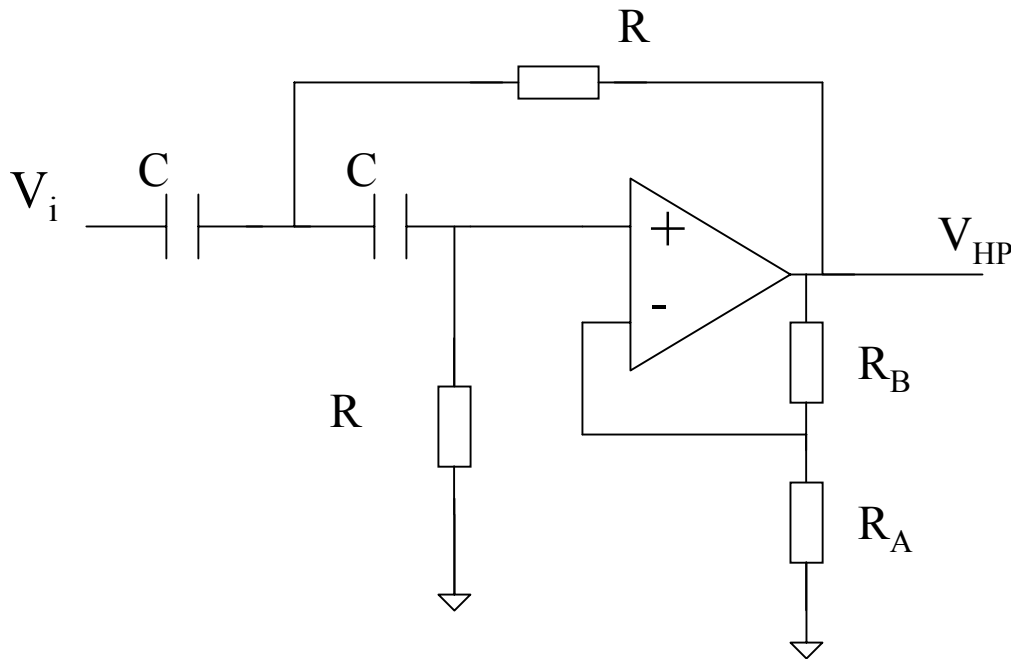


Figure 3: DDA Based Fully-Differential Sallen-Key Filter

Second-Order Active RC Filters



- Sallen-Key Circuits(II)



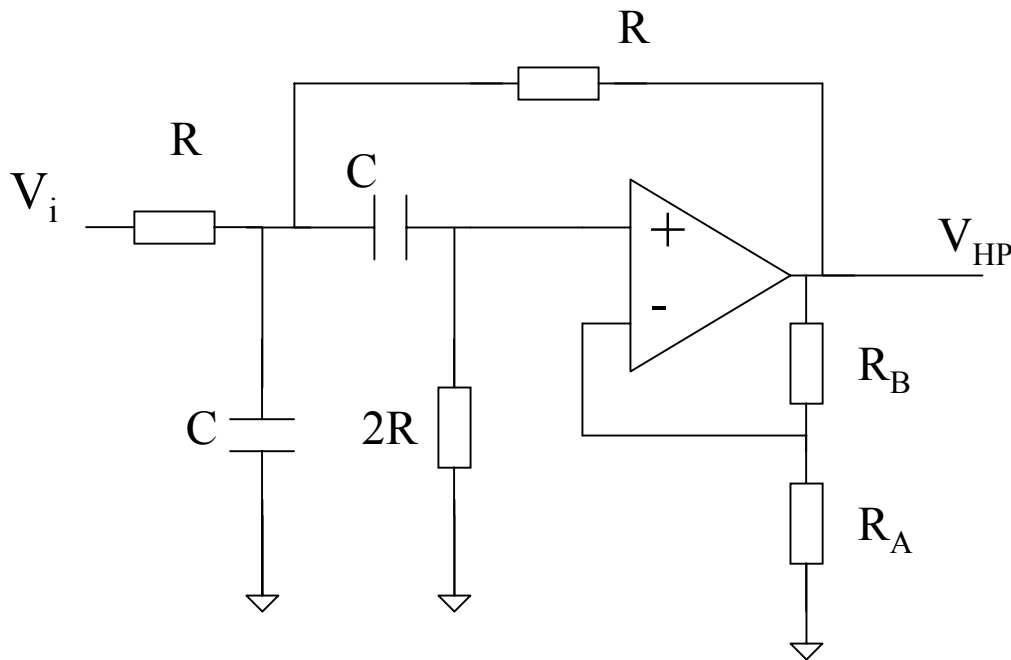
$$H_{HP}(s) = \frac{K \left(\frac{s}{\omega_o}\right)^2}{\left(\frac{s}{\omega_o}\right)^2 + \frac{1}{Q} \left(\frac{s}{\omega_o}\right) + 1}$$

$$\omega_o = 1 / RC$$
$$K = 1 + R_B / R_A$$
$$Q = 1 / (3 - K)$$

Second-Order Active RC Filters



- Sallen-Key Circuits(III)



$$H_{HP}(s) = \frac{K\left(\frac{s}{\omega_o}\right)}{\left(\frac{s}{\omega_o}\right)^2 + \frac{1}{Q}\left(\frac{s}{\omega_o}\right) + 1}$$

$$\omega_o = 1/RC$$

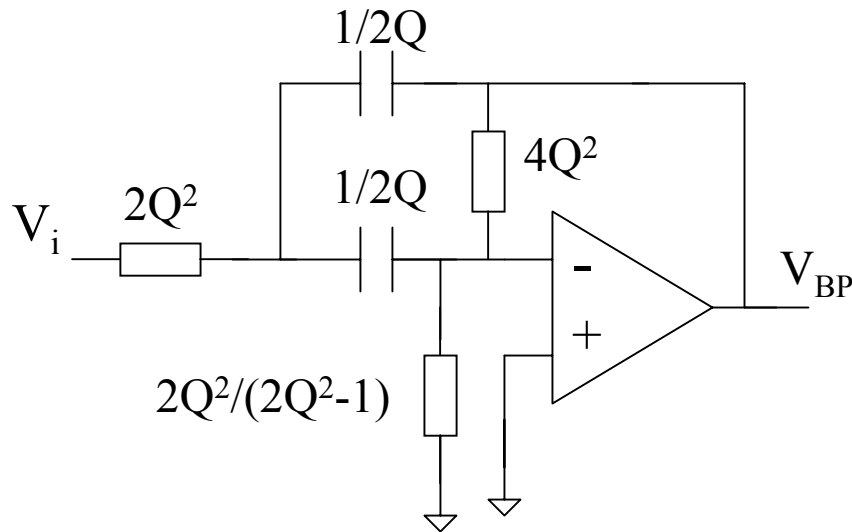
$$K = 1 + R_B / R_A$$

$$Q = 1/(3 - K)$$

Second-Order Active RC Filters



- Delyiannis-Friend Circuits



$$H_{BP}(s) = \frac{s}{s^2 + \frac{1}{Q}s + 1}$$

Cascade Design of High Order Filters



- In general, a high order filter can be implemented by cascading of the first- and second-order filters:

$$H(s) = \frac{\sum_{i=0}^m b_i s^i}{\sum_{i=0}^n b_i s^i} = \left(\prod_{i=1}^l \frac{\alpha_{2i} s^2 + \alpha_{1i} s + \alpha_{0i}}{s^2 + s \frac{\omega_{oi}}{Q_i} + \omega_{oi}^2} \right) \left(\frac{as + b}{s - p} \right)$$
$$= \prod_{i=1}^{l+1} H_i(s)$$